## NSN 5962-01-214-2150

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View Online at https://aerobasegroup.com/nsn/5962-01-214-2150

0.960 inches Body Width: Between 0.220 inches and 0.310 inches Body Height: 0.185 inches	
Between 0.220 inches and 0.310 inches Body Height:	
Body Height:	
0.185 inches	
Maximum Power Dissipation Rating:	
794.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
Features Provided:	
Hermetically sealed and burn in and programmable and schottky and 3-state output	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
12 input	
Case Outline Source And Designator:	
D-6 mil-m-38510	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
7.0 volts power source	
Time Rating Per Chacteristic:	
85.00 nanoseconds propagation delay time, low to high level output and 85.00 nanoseconds propa	agation delay time, high to low level
output	
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Test Data Document:	
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer sta	andards, etc.).
Terminal Type And Quantity:	
18 printed circuit	
Shelf Life:	
N/a	

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

